
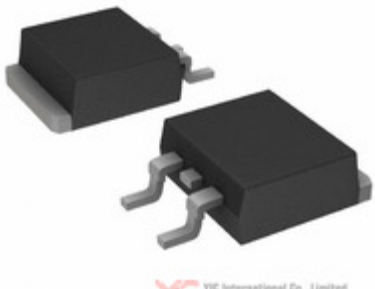
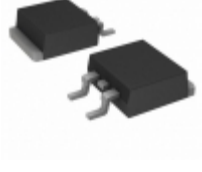







	<p>SUD50N03-09P-E3</p>
	<p>Hersteller-Teilenummer: SUD50N03-09P-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 63A TO252</p> <p>Datenblätter:  SUD50N03-09P-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 4548 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SUD50N03-09P-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 63A TO252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	4548 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	7.5W (Ta), 65.2W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	63A (Tc)
Rds On (Max) @ Id, Vgs	9.5 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	2200pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Original-Reel®

SUD50N03-09P-E3 ist neu im Original, Suche SUD50N03-09P-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD50N03-09P-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SUD50N03-09P-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SUD50N03-09P-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 63A TO252</p>	 <p>SUD50N03-10 VISHAY SUD50N03-10 VISHAY</p>	 <p>SUD50N03-09 VISHAY SUD50N03-09 VISHAY</p>	 <p>SUD50N03-07AP SILICON SUD50N03-07AP SILICON</p>
 <p>SUD50N03-09P VISHAY SUD50N03-09P VISHAY</p>	 <p>SUD50N03-09P-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 63A TO252</p>	 <p>SUD50N03-10-E3 Vishay Precision Group SUD50N03-10-E3 VISHAY</p>	 <p>SUD50N03-07-T4 SILIC SILIC TO-263</p>

heiße Teile

Mehr

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|----------------------|-------------------|----------------------|----------------------|--------------------|
| ⊛ SUD50N024-06P-T4E3 | ↔ SUD50N024-09 | ⇒ SUD50N024-09P | D SUD50N024-09P-E4E3 | ⇒ SUD50N024-09P-T4 |
| ⊠ SUD50N024-09P-T4E3 | ⊛ SUD50N025 | D SUD50N025-05P | ⇒ SUD50N025-06P | ⇒ SUD50N025-06P-E3 |
| ⊛ SUD50N025-06P-E3 | ⊠ SUD50N025-09 | ⊛ SUD50N025-09BP-4E3 | ↔ SUD50N025-09BP-E3 | ⇒ SUD50N03 |
| D SUD50N03-06 | ⊛ SUD50N03-06P | ⊠ SUD50N03-06P-E3 | ⊛ SUD50N03-06P-E3 | ⇒ SUD50N03-07 |
| ⇒ SUD50N03-07AP | ↔ SUD50N03-07P | ⊛ SUD50N03-09 | ⊠ SUD50N03-09P | ⇒ SUD50N03-09P-E3 |
| ↔ SUD50N03-10 | ⇒ SUD50N03-10-T4 | D SUD50N03-10AP | ⊛ SUD50N03-10BP | ⊠ SUD50N03-10BP-T4 |
| ⊛ SUD50N03-10CP | D SUD50N03-10P | ⇒ SUD50N03-11 | ↔ SUD50N03-11-E3 | ⇒ SUD50N03-11-E3 |
| ⊠ SUD50N03-12P | ⊛ SUD50N03-12P-E3 | ↔ SUD50N03-12P-E3 | ⇒ SUD50N03-16P | ⇒ SUD50N03-7M3P |
| ⊛ SUD50N03A | ⊠ SUD50N04-05L | ⊛ SUD50N04-05L-E3 | D SUD50N04-05L-E3 | ⇒ SUD50N04-06H |
| ↔ SUD50N04-06P | ⊛ SUD50N04-07 | ⊠ SUD50N04-07-T4-GE3 | ⊛ SUD50N04-07L | ⇒ SUD50N04-07L-E3 |

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